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DESCRIPTION

The MP5002 is a protection device designed to protect circuitry on the output (V_{OUT}) from transients on the input (V_{IN}). It also protects V_{IN} from undesired shorts and transients coming from the load.

At start up, inrush current is limited by limiting the slew rate at V_{OUT} . The slew rate is controlled by a small capacitor at the dv/dt pin. The dv/dt pin has an internal circuit that allows the customer to float this pin (no connect) and still receive a 1.1ms ramp time at V_{OUT} .

The max load at the output (V_{OUT}) is current limited. This is accomplished by utilizing a sense FET topology. The magnitude of the current limit is controlled by an external resistor connected between the I_{LIMIT} pins.

An internal charge pump drives the gate of the power device, allowing a very low on-resistance DMOS power FET of just 44m Ω .

V_{OUT} is protected from V_{IN} being too low or too high. Under Voltage Lockout (UVLO) assures that the input is above the minimum operating threshold, before the power device is turned on. If V_{IN} goes above the high output threshold, the output voltage will be limited.

FEATURES

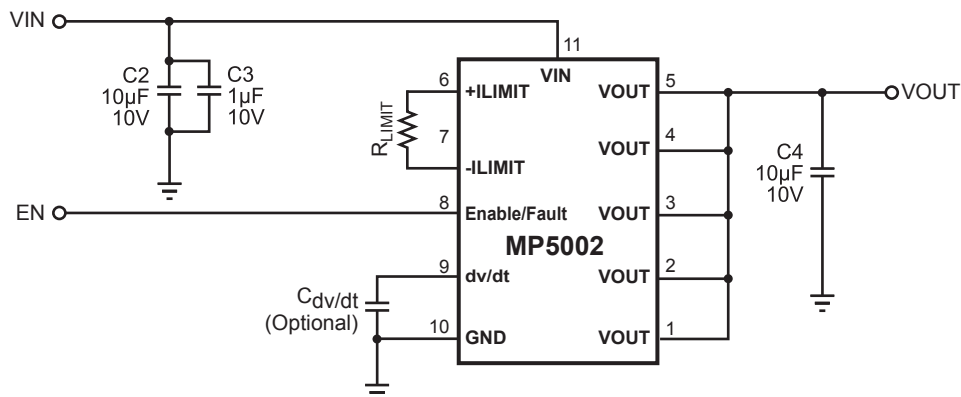
- Integrated 44m Ω Power FET
- Enable/Fault Pin
- Adjustable Slew Rate for Output Voltage
- Adjustable Current Limit: 1A-3A
- Thermal Protection
- Over Voltage Limit

APPLICATIONS

- Hot Swap
- PC Cards
- Cell Phones
- Laptops

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TYPICAL APPLICATION

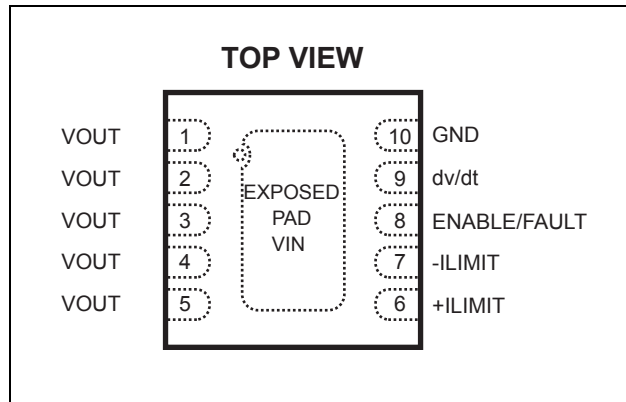


ORDERING INFORMATION

| Part Number* | Package | Top Marking | Free Air Temperature (T _A) |
|--------------|-------------|-------------|--|
| MP5002DQ | QFN10 (3x3) | 3H | -40°C to +85°C |

* For Tape & Reel, add suffix -Z (e.g. MP5002DQ-Z);
 For RoHS compliant packaging, add suffix -LF; (eg. 5002DQ-LF-Z)

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

| | |
|---|-----------------|
| V _{IN} , V _{OUT} , I _{LIMIT} | 22V |
| dv/dt, ENABLE/FAULT | 6V |
| Continuous Power Dissipation (T _A = +25°C) ⁽²⁾ | 2.5W |
| Storage Temperature..... | -65°C to +155°C |
| Junction Temp..... | -40°C to +150°C |

Recommended Operating Conditions

| | |
|--|-----------------|
| Input Voltage Operating Range..... | 2.5V to 4V |
| Operating Junct. Temp (T _J)..... | -40°C to +125°C |

| Thermal Resistance ⁽³⁾ | θ_{JA} | θ_{JC} |
|-----------------------------------|---------------|---------------|
| QFN10 | 50 | 12 ... °C/W |

Notes:

- Exceeding these ratings may damage the device.
- The maximum allowable power dissipation is a function of the maximum junction temperature T_J(MAX), the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D(MAX)=(T_J(MAX)-T_A)/ θ_{JA} . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- Measured on JESD51-7 4-layer board.

ELECTRICAL CHARACTERISTICS

$V_{IN} = 3.3V$, $R_{LIMIT}=24\Omega$, $C_{OUT}= 10\mu F$, $T_J=25^\circ C$, unless otherwise noted.

| Parameters | Symbol | Condition | Min | Typ | Max | Units |
|---|--------------|---|------|------|----------|------------|
| Power FET | | | | | | |
| Delay Time | t_{DLY} | Enabling of chip to $I_D=100mA$ with a 12Ω resistive load | | 0.2 | | ms |
| ON Resistance ⁽⁴⁾ | R_{DSon} | | | 44 | 82 | m Ω |
| | | $T_J=+80^\circ C$ | | 95 | | |
| Off State Output Voltage | V_{OFF} | Enable=0V, $R_L=500\Omega$ | | | 120 | mV |
| Thermal Latch | | | | | | |
| Shutdown Temperature | T_{SD} | | | 175 | | $^\circ C$ |
| Under/Over Voltage Protection | | | | | | |
| Output Clamping Voltage | V_{CLAMP} | Overvoltage Protection $V_{IN} = 6V$ | 4 | 4.5 | 5.0 | V |
| Under Voltage Lockout | V_{UVLO} | Turn on, Voltage going high | 2.15 | 2.35 | 2.5 | V |
| Under Voltage Lockout (UVLO) Hysteresis | V_{HYST} | | | 100 | | mV |
| Current Limit | | | | | | |
| Short Circuit Current Limit ⁽⁴⁾ (Hold Current) | I_{LIM} | $R_{LIMIT}=24\Omega$ | 1.2 | 1.55 | 1.9 | A |
| Trip Current | I_{LIM-OL} | $R_{LIMIT}=24\Omega$ | | 2.5 | | A |
| dv/dt Circuit | | | | | | |
| Rise Time | T_r | Float dv/dt pin, Note 5 | 0.64 | 1.1 | 2.0 | ms |
| Enable/Fault | | | | | | |
| Low Level Input Voltage | V_{IL} | Output Disabled | | | 0.5 | V |
| Intermediate Level Input Voltage | $V_{I(INT)}$ | Thermal Fault, Output Disabled | 0.8 | 1.4 | 2.0 | V |
| High Level Input Voltage | V_{IH} | Output Enabled | 2.5 | | | V |
| High State Maximum Voltage | $V_{I(MAX)}$ | | | 3.25 | | V |
| Low Level Input Current (Sink) | I_{IL} | $V_{ENABLE}=0V$ | | -28 | -50 | μA |
| Maximum Fanout for Fault Signal | | Total number of chips that can be connected for simultaneous shutdown | | | 3 | Units |
| Maximum Voltage on Enable Pin | V_{MAX} | Note 6 | | | V_{IN} | V |
| Total Device | | | | | | |
| Bias Current | I_{BIAS} | Device Operational | | 1.5 | 2.0 | mA |
| | | Thermal Shutdown | | 0.9 | | |
| Minimum Operating Voltage for UVLO | V_{MIN} | Enable<0.5V | | | 2.0 | V |

Notes:

- 4) Guaranteed by design.
- 5) Measured from 10% to 90%.
- 6) Maximum Input Voltage to be $\leq 6.0V$ if $V_{IN} \geq 6.0V$. Maximum Input Voltage to be V_{IN} if $V_{IN} \leq 6.0V$.

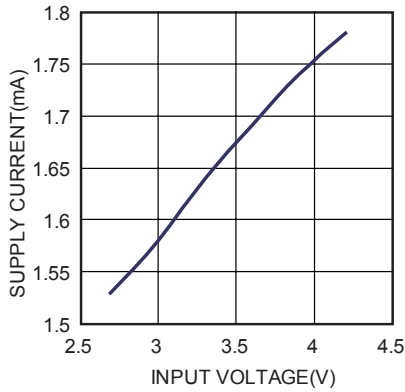
PIN FUNCTIONS

| Pin # | Name | Description |
|-------|--------------|--|
| 1-5 | VOUT | This pin is the V_{OUT} of the internal power FET and the output terminal of the IC. |
| 6 | +ILIMIT | A resistor between these pins sets the overload and short circuit current limit levels. |
| 7 | -ILIMIT | A resistor between these pins sets the overload and short circuit current limit levels. |
| 8 | Enable/Fault | The Enable/Fault pin is a tri-state, bi-directional interface. It can be used to enable the output of the device by floating the pin, or disable the chip by pulling it to ground (using an open drain or open collector device). If a thermal fault occurs, the voltage on this pin will go to an intermediate state to signal a monitoring circuit that the device is in thermal shutdown. |
| 9 | dv/dt | The internal dv/dt circuit controls the slew rate of the output voltage at turn on. It has an internal capacitor that allows it to ramp up over the period of 1.1ms. An external capacitor can be added to this pin to increase the ramp time. If an additional time delay is not required, this pin should be left open. |
| 10 | GND | Negative Input Voltage to the Device. This is used as the internal reference for the IC. |
| 11 | VIN | Positive input voltage to the device (Exposed Pad). |

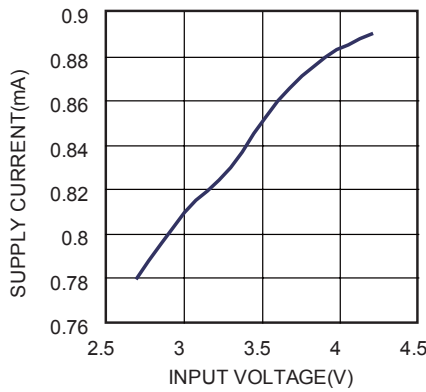
TYPICAL PERFORMANCE CHARACTERISTICS

$V_{IN} = 3.3V$, $V_{EN} = 3.3V$, $R_{LIMIT} = 24\Omega$, $C_{OUT} = 10\mu F$, $Cdv/dt = 1nF$, $T_A = 25^\circ C$, unless otherwise noted.

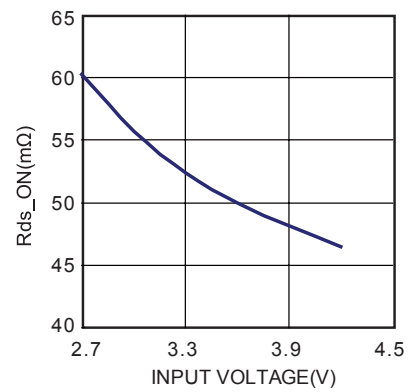
Supply Current, Output Enabled vs. Input Voltage
no load, EN floating



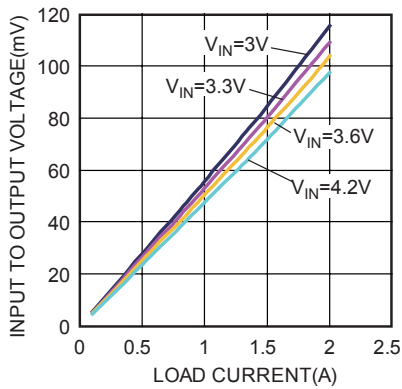
Supply Current, Output Disabled vs. Input Voltage
 $V_{EN} = 0$



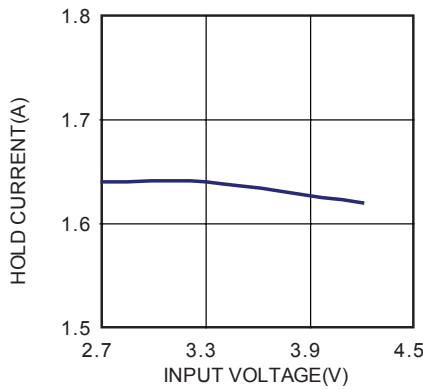
Static Drain-Source On-State Resistance vs. Input Voltage
 $I_{OUT} = 1A$



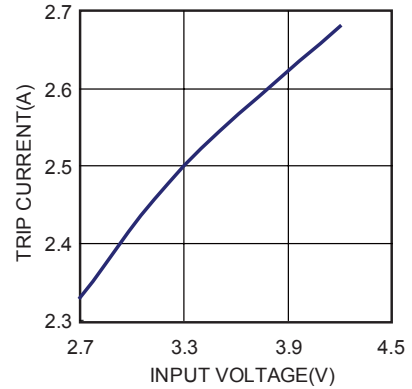
Input to Output Voltage vs. Load Current



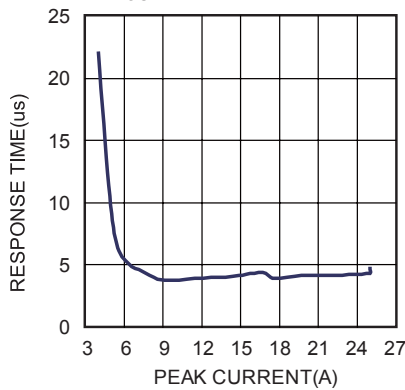
Hold Current vs. Input Voltage
 $R_{LIMIT} = 24\Omega$



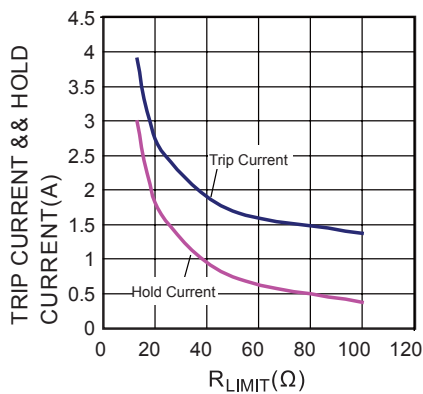
Threshold Trip Current vs. Input Voltage
 $R_{LIMIT} = 24\Omega$



Current Limit Response vs. Peak Current
no C_{OUT}



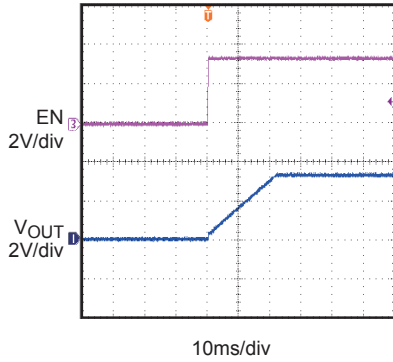
Trip and Hold Current vs. R_{LIMIT}



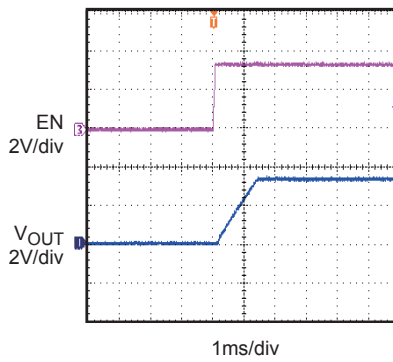
TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 3.3V$, $V_{EN} = 3.3V$, $R_{LIMIT} = 24\Omega$, $C_{OUT} = 10\mu F$, $C_{dv/dt} = 1nF$, $T_A = 25^\circ C$, unless otherwise noted.

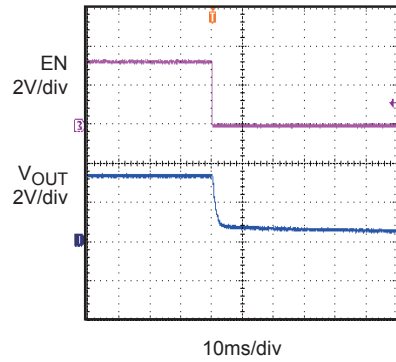
Turn on Delay and Rise Time with 1uF Load
 $C_{OUT} = 1\mu F$, no load



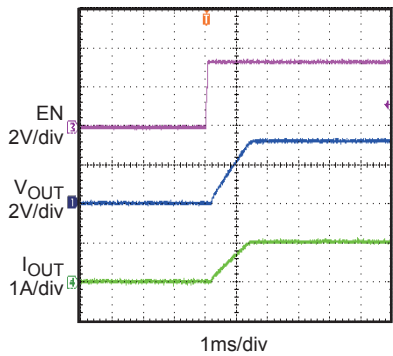
Turn on Delay and Rise Time with 1uF Load, no Cdv/dt
 $C_{OUT} = 1\mu F$, no load



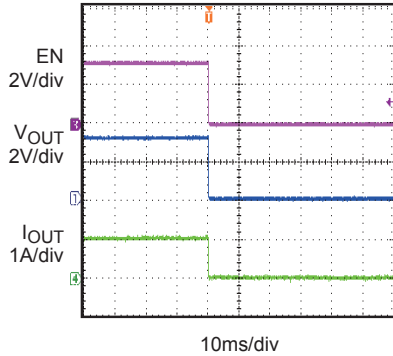
Turn off Delay and Fall Time with 1uF Load
 $C_{OUT} = 1\mu F$, no load



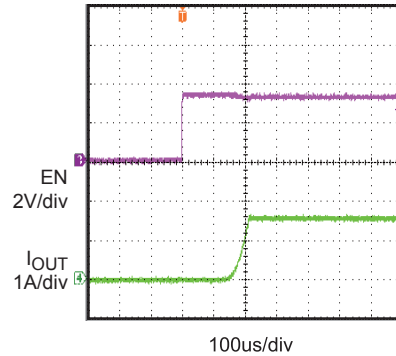
Turn on Delay and Rise Time with 3.3Ω and 10uF Load
 $R_{LOAD} = 3.3\Omega$, no Cdv/dt



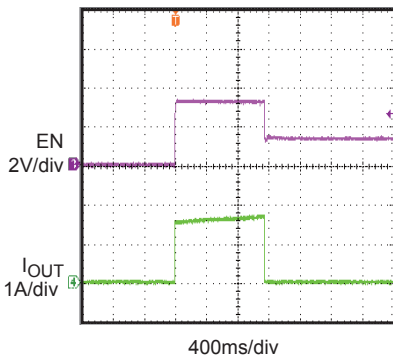
Turn off Delay and Fall Time with 3.3Ω and 10uF Load
 $R_{LOAD} = 3.3\Omega$, no Cdv/dt



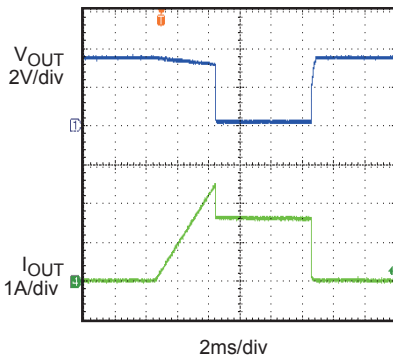
Short Circuit Current, Device Enabled into Short



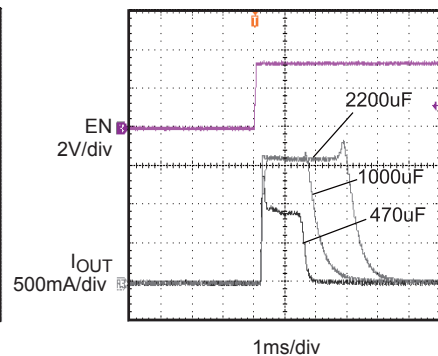
Short Circuit Current, Device Enabled into Short, and Thermal Shut down
 EN floating



Trip Current with Ramped Load on Enabled Device



Inrush Current with Different Load Capacitance
 no Cdv/dt, no Load

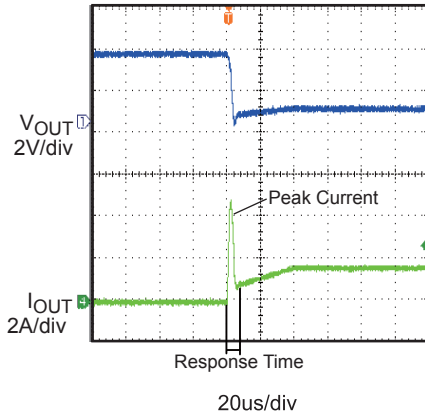


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 3.3V$, $V_{EN} = 3.3V$, $R_{LIMIT} = 24\Omega$, $C_{OUT} = 10\mu F$, $C_{dv/dt} = 1nF$, $T_A = 25^\circ C$, unless otherwise noted.

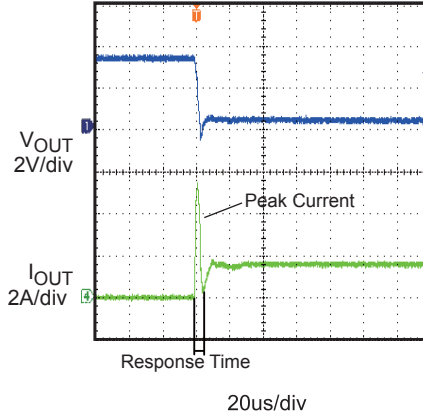
0.33Ω Load Connected to Enabled Device

no C_{OUT}



0.17Ω Load Connected to Enabled Device

no C_{OUT}



BLOCK DIAGRAM

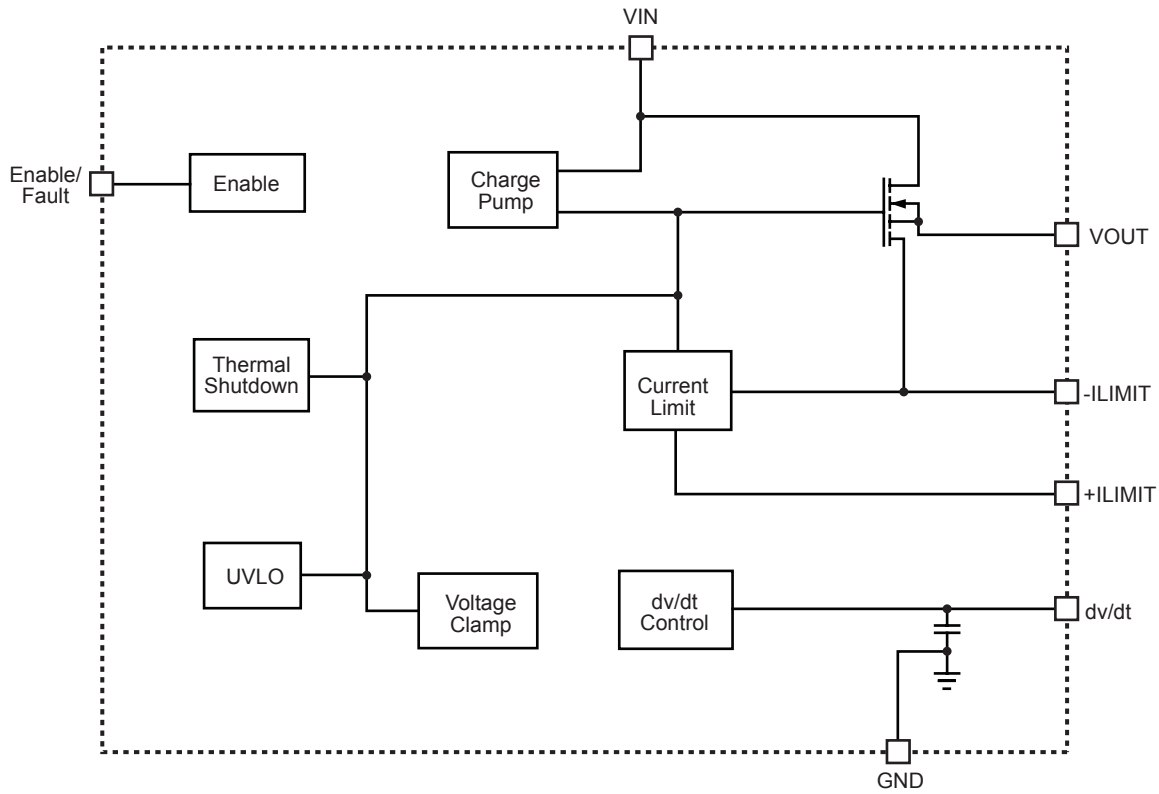


Figure 1—Functional Block Diagram

CURRENT LIMIT

The desired current limit is a function of the external current limit resistor.

Table 1—Current Limit vs. Current Limit Resistor
($V_{IN}=3.3V$)

| Current Limit Resistor (Ω) | 13 | 24 | 50 | 100 |
|-------------------------------------|------|------|------|------|
| Trip Current (A) | 3.90 | 2.50 | 1.70 | 1.37 |
| Hold Current (A) | 2.99 | 1.55 | 0.74 | 0.37 |

When the part is active, if load reaches trip current (minimum threshold current triggering overcurrent protection) or a short is present, the part switches into to a constant-current (hold current) mode. Part will be shutdown only if the overcurrent condition stays long enough to trigger thermal protection.

However, when the part is powered up by V_{CC} or EN, the load current should be smaller than hold current. Otherwise, the part can't be fully turned on.

In a typical application using a current limit resistor of 24Ω , the trip current will be 2.5A and the hold current will be 1.55A. If the device is in its normal operating state and passing 1.5A it will need to dissipate only 99mW with the very low on resistance of $44m\Omega$. For the package dissipation of $50^{\circ}C/Watt$, the temperature rise will only be $+5^{\circ}C$. Combined with a $25^{\circ}C$ ambient, this is only $30^{\circ}C$ total package temperature.

During a short circuit condition, the device now has 3.3V across it and the hold current clamps at 1.55A and therefore must dissipate 5W. At $50^{\circ}C/watt$, if uncontrolled, the temperature would rise above the thermal protection threshold ($+175^{\circ}C$) and the device will shutdown to cause the temperature to drop.

Proper heat sink must be used if the device is intended to supply the hold current and not shutdown. Without a heat sink, hold current should be maintained below 909mA at $+25^{\circ}C$ and below 545mA at $+85^{\circ}C$ to prevent the device from activating the thermal shutdown feature.

RISE TIME

The rise time is a function of the capacitor ($C_{dv/dt}$) on the dv/dt pin.

Table 2—Rise Time vs. $C_{dv/dt}$

| $C_{dv/dt}$ | none | 50pF | 500pF | 1nF |
|--------------------------|------|------|-------|------|
| Rise Time (TYPICAL) (ms) | 1.1 | 2.2 | 12.3 | 23.5 |

* Notes: Rise Time = $K_{RT} * (50pF + C_{dv/dt})$, $K_{RT} = 22E6$

The “rise time” is measured by from 10% to 90% of output voltage.

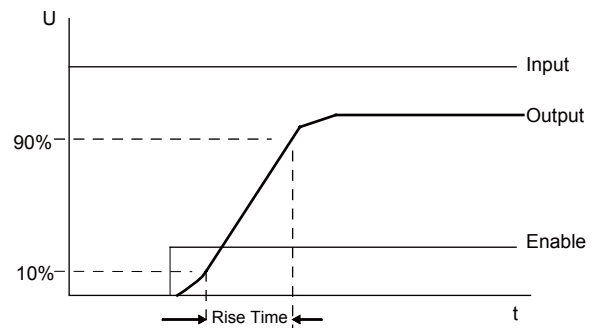


Figure 2—Rise Time

FAULT AND ENABLE PIN

The Enable/Fault Pin is a Bi-Directional three level I/O with a weak pull up current (25uA typical). The three levels are low, mid and high. It functions to enable/disable the part and to relay Fault information.

Enable pin as an input:

1. Low and mid disable the part.
2. Low, in addition to disabling the part, clears the fault flag.
3. High enables the part (if the fault flag is clear).

Enable pin as an output:

1. The pull up current may (if not overridden) allow a “wired nor” pull up to enable the part.
2. An under voltage will cause a low on the enable pin, and will clear the fault flag.
3. A thermal fault will cause a mid level on the enable pin, and will set the fault flag.

The Enable/Fault line must be above the mid level for the output to be turned on.

The fault flag is an internal flip-flop that can be set or reset under various conditions:

1. Thermal Shutdown: set fault flag
2. Under Voltage: reset fault flag
3. Low voltage on Enable/Fault pin: reset fault flag
4. Mid voltage on Enable/Fault pin: no effect

5. Under a fault, the Enable/Fault pin is driven to the mid level.

There are 4 types of faults, and each fault has a direct and indirect effect on the Enable/Fault pin and the internal fault flag. In a typical application where there are multiple MP5002 chips in a system, the enable/fault lines are typically connected together.

Table 3—Fault Function Influence in Application

| Fault description | Internal action | Effect on Fault Pin | Effect on Flag | Effect on secondary Part |
|--------------------|---|---|----------------|---|
| Short/over current | Limit current | none | none | none |
| Under Voltage | Output is turned off | Internally drives Enable/Fault pin to Logic low | Flag is reset | Secondary part output is disabled, and fault flag is reset. |
| Over Voltage | Limit output voltage | None | None | None |
| Thermal Shutdown | Shutdown part. The part is latched off until a UVLO or externally driven to ground. | Internally drives Enable/Fault pin to mid level | Flag is Set | Secondary part output is disabled. |

UNDER VOLTAGE LOCK OUT OPERATION

If the supply (input) is below the UVLO threshold, the output is disabled, and the fault line is driven low. When the supply goes above the UVLO threshold, the output is enabled and the fault line is released. When the fault line is released it will be pulled high by a 25uA current V_{OUT} . No external pull up resistor is required. In addition, the pull up voltage is limited to 5 volts.

THERMAL PROTECTION

When thermal protection is triggered, the output is disabled and the fault line is driven to the mid level. The thermal fault condition is latched (meaning the fault flag is set), and the part will remain latched off until the fault (enable) line is brought low. Cycling the power below the UVLO threshold will also reset the fault flag.

PCB LAYOUT

PCB layout is very important to achieve stable operation. Please follow these guidelines and take below figure for reference.

Place R_{limit} close to I_{limit} pin, C_{dv/dt} close to dv/dt pin and input cap close to VIN (Exposed Pad). Keep the N/C pin float. Put vias in thermal pad and ensure enough copper area near VIN and VOUT to achieve better thermal performance.

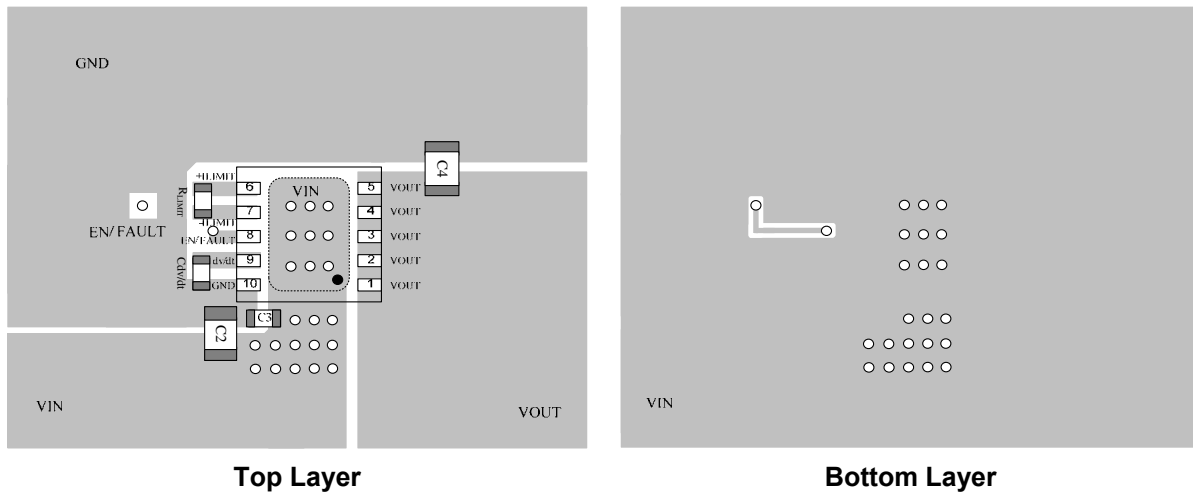
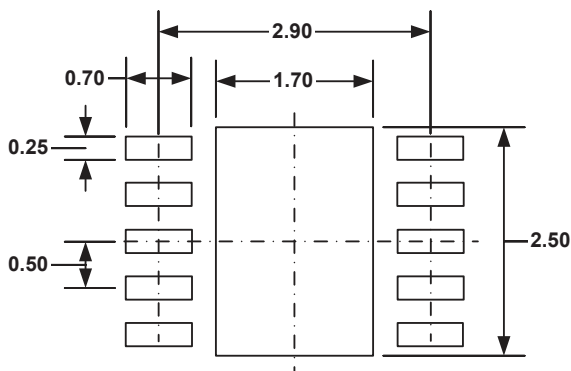
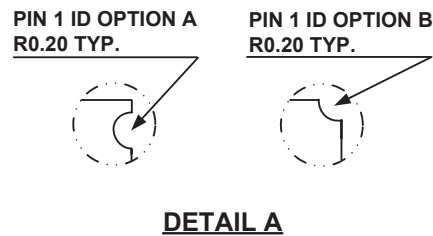
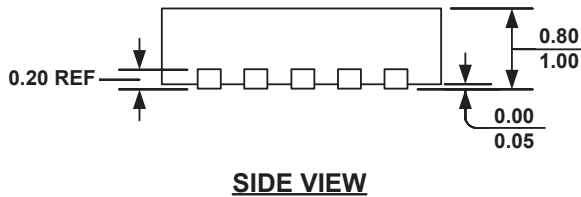
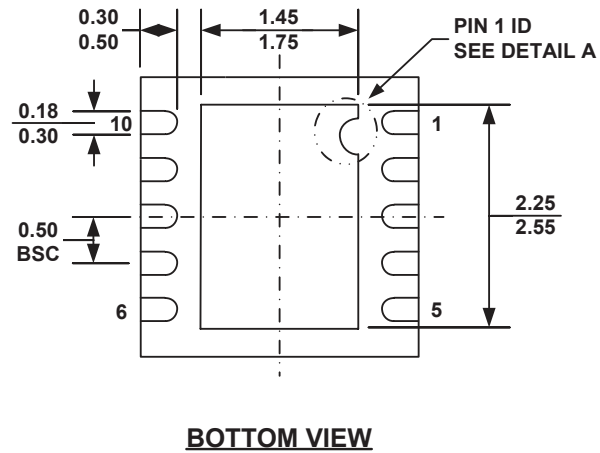
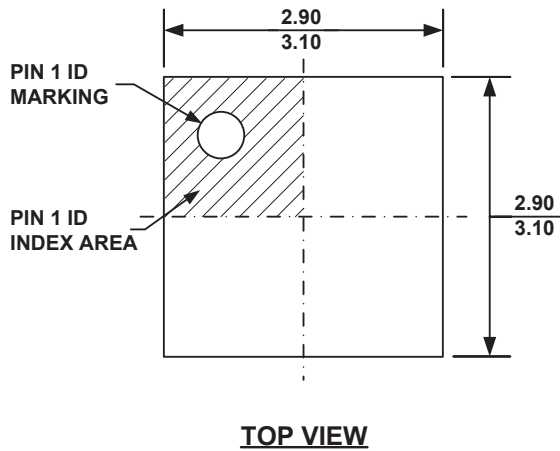


Figure 3—PCB Layout

PACKAGE INFORMATION

QFN10 (3mm x 3mm)



NOTE:

- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
- 3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETER MAX.
- 4) DRAWING CONFORMS TO JEDEC MO-229, VARIATION VEED-5.
- 5) DRAWING IS NOT TO SCALE.

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